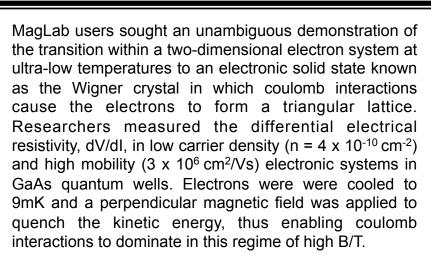
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Pinning and melting of a quantum Wigner crystal

T. Knighton¹, Z. Wu¹, J. Huang¹, A. Serafin², J.-S. Xia², K.W. Baldwin³, K.W. West³

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The measurements revealed a striking threshold behavior for T \leq 35 mK that evidences the formation of the Wigner crystal. The crystal is pinned (i.e. resistance > 1 GΩ) by disorder only at extremely low currents with magnitude < 5 pA. At currents just above the pinning threshold, the resistance plummets by more than an order of magnitude. The pinning is also destroyed by heating, consistent with the thermal melting of the Wigner crystal.

The temperature dependence was found to be nonactivated and piecewise, implying the existence of a pinned Wigner crystal that appears to undergo a twostage first-order transition upon heating.

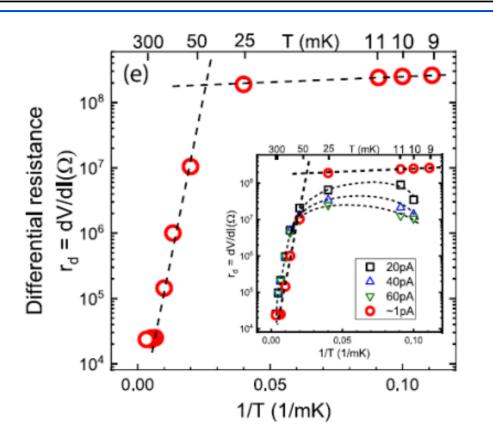


Figure: Temperature dependence of the differential resisitivity, dV/dI, in the limit of $V \rightarrow 0$, plotted on a semilogarithmic scale. Inset: comparison of the differential resistivity obtained with higher current drives.

